

June 2007

# FAN5308 800mA High-Efficiency Step-Down DC-DC Converter

### **Features**

- 96% efficiency, synchronous operation
- Adjustable output voltage options from 0.8V to V<sub>IN</sub>
- 2.5V to 5.5V input voltage range
- Up to 800mA output current
- Fixed-frequency 1.3MHz PWM operation
- High-efficiency, power-save mode
- 100% duty cycle low-dropout operation
- Soft-start
- Output over-voltage protection
- Dynamic output voltage positioning
- 25µA quiescent current
- Thermal shutdown and short-circuit protection
- Pb-free 3x3mm 6-lead MLP package

# **Applications**

- Pocket PCs, PDAs
- Cell phones
- Battery-powered portable devices
- Digital cameras
- Hard disk drives
- Set-top boxes
- Point-of-load power
- Notebook computers
- Communications equipment

## **Description**

Designed for use in battery-powered applications, the FAN5308 is a high-efficiency, low-noise synchronous PWM current mode and pulse skip (power-save) mode DC-DC converter. It can provide up to 800mA of output current over an input range from 2.5V to 5.5V. The output voltage can be externally adjusted over a range of 0.8V to 5.5V by means of an external voltage divider.

At moderate and light loads, pulse skipping modulation is used. Dynamic voltage positioning is applied and the output voltage is shifted 0.8% above nominal value for increased headroom during load transients. At higher loads, the system automatically switches over to current mode PWM control, operating at 1.3MHz. A current mode control loop with fast transient response ensures excellent line and load regulation. To achieve high efficiency and ensure long battery life, the quiescent current is reduced to  $25\mu A$  in power-save mode, and the supply current drops below  $1\mu A$  in shut-down mode. The FAN5308 is available in a 3x3mm 6-lead MLP package.

# **Ordering Information**

Product Number	Output Voltage	Package Type	Order Code
FAN5308	Adjustable	3x3mm 6-Lead MLP	FAN5308MPX

# **Typical Application**

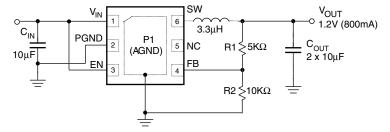


Figure 1. Typical Application

# **Pin Configuration**

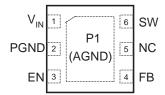


Figure 2. Pin Assignment for 3x3mm 6-Lead MLP

# **Pin Description**

Pin #	Name	Description
P1	AGND	Analog Ground. P1 must be soldered to the PCB ground.
1	V <sub>IN</sub>	Supply Voltage Input.
2	PGND	<b>Power Ground.</b> This pin is connected to the internal MOSFET switches. This pin must be externally connected to AGND.
3	EN	<b>Enable Input.</b> Logic high enables the chip and logic low disables the chip, reducing the supply current to less than 1μA. Do not float this pin.
4	FB	Feedback Input. Adjustable voltage option, connect this pin to the resistor divider.
5	NC	No Connection Pin.
6	SW	Switching Node. This pin is connected to the internal MOSFET switches.

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Parameter			Max.	Unit
V <sub>IN</sub>		-0.3	7.0	V
Voltage On Any Other Pin		-0.3	V <sub>IN</sub>	V
Lead Soldering Temperature (10 seconds)			260	°C
Junction Temperature			150	°C
Storage Temperature		-65	150	°C
Thermal Resistance, Junction-to-Case (θ <sub>JC</sub> ), 3x3mm 6-lead MLP <sup>(1)</sup>			8	°C/W
Electrostatic Discharge Protection (ESD) Level <sup>(2)</sup>		4		kV
Lieutiostatic Discharge Frotection (ESD) Level	CDM	1		] ^v

#### Notes:

- 1. Junction-to-ambient thermal resistance,  $\theta_{JA}$ , is a strong function of PCB material, board thickness, thickness and number of copper planes, number of via used, diameter of via used, available copper surface, and attached heat sink characteristics.
- 2. Using Mil Std. 883E, method 3015.7 (Human Body Model) and EIA/JESD22C101-A (Charged Device Model).

# **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Parameter	Min.	Тур.	Max.	Unit
Supply Voltage Range	2.5		5.5	V
Output Voltage Range, Adjustable Version	0.8		V <sub>IN</sub>	V
Output Current			800	mA
Inductor <sup>(3)</sup>		3.3		μH
Input Capacitor <sup>(3)</sup>		10		μF
Output Capacitor <sup>(3)</sup>		2 x 10		μF
Operating Ambient Temperature Range	-40		+85	°C
Operating Junction Temperature Range	-40		+125	°C

#### Note:

3. Refer to the Applications section for details.

## **Electrical Characteristics**

 $V_{IN}$  =  $V_{OUT}$  + 0.6V (minimum 2.5V) to 5.5V,  $I_{OUT}$  = 350mA,  $V_{OUT}$  =1.2V, EN =  $V_{IN}$ ,  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Units
V <sub>IN</sub>	Input Voltage	$0 \text{ mA} \le I_{OUT} \le 800 \text{ mA}$		2.5		5.5	V
		I <sub>OUT</sub> = 0mA, Device is not switching			20	35	μA
IQ	Quiescent Current	I <sub>OUT</sub> = 0mA, Device	R2 =10kΩ		50		μA
		is switching <sup>(4)</sup>	R2 =100kΩ		25		μA
I <sub>SD</sub>	Shutdown Supply Current	EN = GND			0.1	1.0	μA
V	Under-Voltage Lockout	V <sub>IN</sub> Rising		1.9	2.1	2.3	V
V <sub>UVLO</sub>	Threshold	Hysteresis			150		mV
V <sub>ENH</sub>	Enable High Input Voltage			1.3			V
V <sub>ENL</sub>	Enable Low Input Voltage					0.4	V
I <sub>EN</sub>	EN Input Bias Current	$EN = V_{IN}$ or $GND$			0.01	0.10	μA
	PMOS On Resistance	$V_{IN} = V_{GS} = 5.5V$			250 350	mΩ	
<b>D</b>	FIVIOS OII RESISTANCE	$V_{IN} = V_{GS} = 2.5V$			300	400	11122
R <sub>DS-ON</sub>	NMOS On Resistance	$V_{IN} = V_{GS} = 5.5V$	GS = 5.5V 200		300	mΩ	
	NIVIOS OF RESISTANCE	$V_{IN} = V_{GS} = 2.5V$			250	350	1117.5
I <sub>LIM</sub>	P-channel Current Limit	2.5V < V <sub>IN</sub> < 5.5V		1300	1500	2000	mA
fosc	Oscillator Frequency			1000	1300	1500	KHz
I <sub>lkg_(N)</sub>	N-Channel Leakage Current	V <sub>DS</sub> = 5.5V			0.1	1	μA
I <sub>lkg_(P)</sub>	P-Channel Leakage Current	V <sub>DS</sub> = 5.5V			0.1	1	μA
	Line Regulation	I <sub>OUT</sub> = 10mA			0.16		%/V
	Load Regulation	egulation 350mA ≤ I <sub>OUT</sub> ≤ 800mA			0.15		%
V <sub>REF</sub>	Reference Voltage				0.8		V
	Output DC Voltage Accuracy <sup>(5)</sup>	$0mA \le I_{OUT} \le 800mA$		-3		+3	%
	Over-Temperature Protection	PWM Mode Only 350mA ≤ I <sub>OUT</sub> ≤	Rising Temperature		150		°C
	TOGOTION	800mA	Hysteresis	-	20		°C
t <sub>ST</sub>	Start-Up Time	$I_{OUT} = 800 \text{mA}, C_{OUT} = 20 \mu \text{F}$			800		μs

## Notes:

- 4. Refer to the Application section for details.
- 5. For output voltages  $\leq$  1.2V, a 40 $\mu$ F output capacitor value is required to achieve a maximum output accuracy of 3% while operating in power-save mode (PFM mode).

# **Typical Performance Characteristics**

 $T_A$  = 25°C,  $C_{IN}$  = 10 $\mu$ F,  $C_{OUT}$  = 20 $\mu$ F, L = 3.3 $\mu$ H,  $R_2$  = 10 $k\Omega$ , unless otherwise noted.

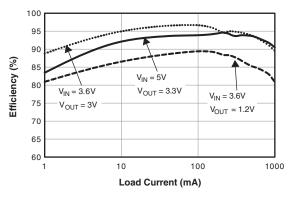


Figure 3. Efficiency vs. Load Current

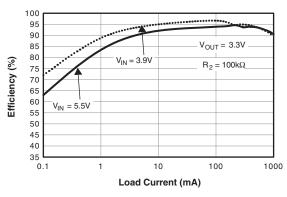


Figure 4. Efficiency vs. Load Current

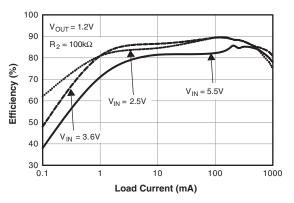


Figure 5. Efficiency vs. Load Current

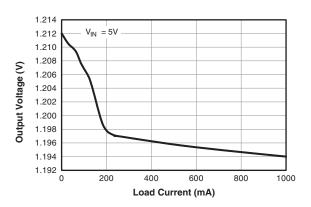


Figure 6. Output Voltage vs. Load Current

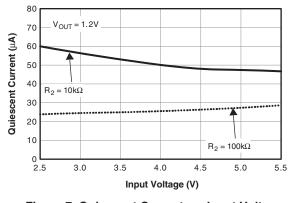


Figure 7. Quiescent Current vs. Input Voltage

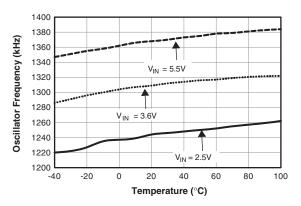


Figure 8. Frequency vs. Temperature

# **Typical Performance Characteristics** (Continued)

 $T_A = 25$ °C,  $C_{IN} = 10\mu$ F,  $C_{OUT} = 20\mu$ F,  $L = 3.3\mu$ H,  $R_2 = 10k\Omega$ , unless otherwise noted.

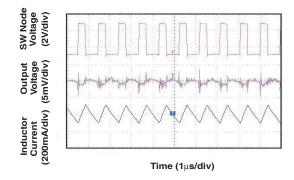
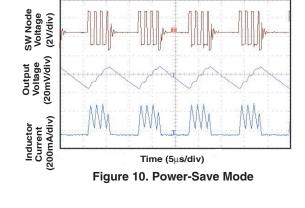


Figure 9. PWM Mode



Output Inductor Load Current Step (50mV/div) (50mV/div) (50mV/div) (10μs/div)

Figure 11. Load Transient Response

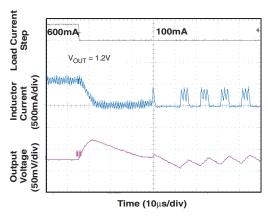


Figure 12. Load Transient Response

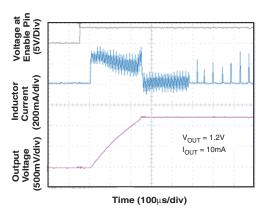


Figure 13. Start-Up Response

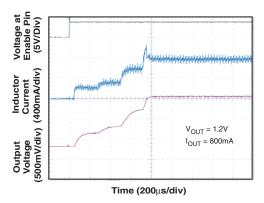


Figure 14. Start-Up Response

## **Block Diagram**

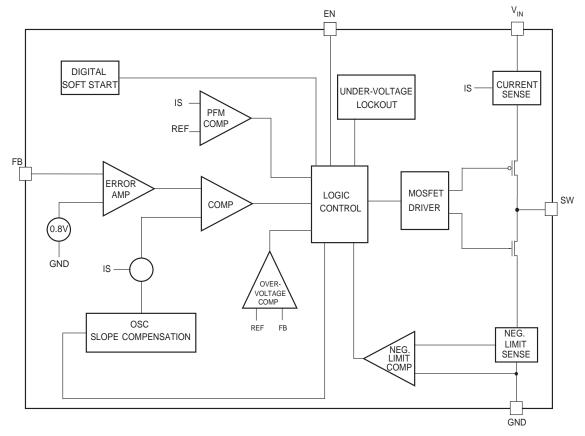


Figure 15. Block Diagram

## **Detailed Operation Description**

The FAN5308 is a step-down converter operating in a current-mode PFM/PWM architecture with a typical switching frequency of 1.3MHz. At moderate to heavy loads, the converter operates in pulse-width-modulation (PWM) mode. At light loads, the converter enters a power-save mode (PFM pulse skipping) to keep the efficiency high.

#### **PWM Mode**

In PWM mode, the device operates at a fixed frequency of 1.3MHz. At the beginning of each clock cycle, the P-channel transistor is turned on. The inductor current ramps up and is monitored via an internal circuit. The P-channel switch is turned off when the sensed current causes the PWM comparator to trip when the output voltage is in regulation or when the inductor current reaches the current limit (set internally to typically 1500mA). After a minimum dead time, the N-channel transistor is turned on and the inductor current ramps down. As the clock cycle is completed, the N-channel switch is turned off and the next clock cycle starts.

## PFM (Power-Save) Mode

As the load current decreases and the inductor current reaches negative value, the converter enters pulse-frequency-modulation (PFM) mode. The transition point for the PFM mode is given by the equation:

$$I_{OUT} = V_{OUT} \times \frac{1 - (V_{OUT} / V_{IN})}{2 \times L \times f}$$
 EQ. 1

The typical output current, when the device enters PFM mode, is 150mA for input voltage of 3.6V and output voltage of 1.2V. In PFM mode, the device operates with a variable frequency and constant peak current, thus reducing the quiescent current to minimum. Consequently, the high efficiency is maintained at light loads. As soon as the output voltage falls below a threshold, set at 0.8% above the nominal value, the P-channel transistor is turned on and the inductor current ramps up. The P-channel switch turns off and the N-channel turns on as the peak inductor current is reached (typical 450mA).

The N-channel transistor is turned off before the inductor current becomes negative. At this time, the P-channel is switched on again, starting the next pulse. The converter continues these pulses until the high threshold (typical 1.6% above nominal value) is reached. A higher output voltage in PFM mode gives additional headroom for the voltage drop during a load transient from light to full load. The voltage overshoot during this load transient is also minimized due to active regulation during turn on of the N-channel rectifier switch. The device stays in sleep mode until the output voltage falls below the low threshold. The FAN5308 enters the PWM mode as soon as the output voltage can no longer be regulated in PFM with constant peak current.

## 100% Duty Cycle Operation

As the input voltage approaches the output voltage and the duty cycle exceeds the typical 95%, the converter turns the P-channel transistor continuously on. In this mode, the output voltage is equal to the input voltage, minus the voltage drop across the P-channel transistor:

$$V_{OUT} = V_{IN} - I_{LOAD} \times (R_{dsON} + R_L)$$
 EQ. 2

where:

 $R_{dsON}$  = P-channel switch on resistance  $I_{LOAD}$  = Output current  $R_L$  = Inductor DC resistance

#### **UVLO and Soft Start**

The reference and the circuit remain reset until the  $V_{\mbox{\scriptsize IN}}$  crosses its UVLO threshold.

The FAN5308 has an internal soft-start circuit that limits the inrush current during start-up. This prevents possible voltage drops of the input voltage and eliminates the output voltage overshoot. The soft-start is implemented as a digital circuit, increasing the switch current in four steps to the P-channel current limit (1500mA). Typical start-up time for a  $20\mu F$  output capacitor and a load current of 800mA is  $800\mu s$ .

#### **Short-Circuit Protection**

The switch peak current is limited cycle-by-cycle to a typical value of 1500mA. In the event of an output voltage short circuit, the device operates with a frequency of 400kHz and minimum duty cycle; therefore, the average input current is typically 200mA.

#### **Thermal Shutdown**

When the die temperature exceeds 150°C, a reset occurs and remains in effect until the die cools to 130°C. At that time, the circuit is allowed to restart.

# **Applications Information**

## **Setting the Output Voltage**

The internal reference is 0.8V (typical). The output voltage is divided by a resistor divider, R1 and R2 to the FB pin. The output voltage is given by:

$$V_{OUT} = V_{REF} \times \left(1 + \left(\frac{R1}{R2}\right)\right)$$
 EQ. 3

where  $R_1 + R_2 < 800K\Omega$ .

According to this equation, and assuming desired output voltage of 1.5096V, and given R2 =  $10k\Omega$ , the calculated value of R1 is  $8.87k\Omega$ . If quiescent current is a key design parameter, a higher value feedback resistor can be used (e.g. R2 =  $100k\Omega$ ) and a small bypass capacitor of 10pF is required in parallel with the upper resistor, as shown in Figure 16.

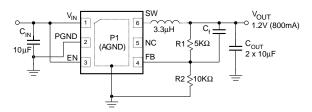


Figure 16. Setting the Output Voltage

#### **Inductor Selection**

The inductor parameters directly related to the device's performances are saturation current and DC resistance. The FAN5308 operates with a typical inductor value of 3.3µH. The lower the DC resistance, the higher the efficiency. For saturation current, the inductor should be rated higher than the maximum load current plus half of the inductor ripple current.

This is calculated as follows:

$$\Delta I_{L} = V_{OUT} \times \frac{1 - (V_{OUT} / V_{IN})}{L \times f}$$
 Eq. 4

where:

 $\Delta I_1$  = Inductor Ripple Current

f = Switching Frequency

L = Inductor Value

Inductor Value	Vendor	Part Number
3.3µH	Panasonic	ELL6PM3R3N
3.3µH	Murata	LQS66C3R3M04

**Table 1: Recommended Inductors** 

## **Capacitors Selection**

For best performances, a low-ESR input capacitor is required. A ceramic capacitor of at least  $10\mu F$ , placed close to the  $V_{1N}$  and AGND pins, is recommended. The output capacitor determines the output ripple and the transient response.

Capacitor Value	Vendor	Part Number
10µF	Taiyo	JMK212BJ106MG
	Yuden	JMK316BJ106KL
	TDK	C2012X5ROJ106K
		C3216X5ROJ106M
	Murata	GRM32ER61C106K

**Table 2: Recommended Capacitors** 

### **PCB Layout Recommendations**

The recommended PCB layout is shown in Figure 17. The inherently high peak currents and switching frequency of power supplies require careful PCB layout design.

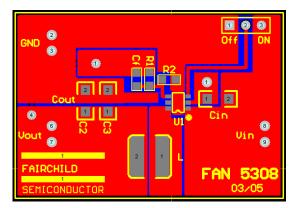


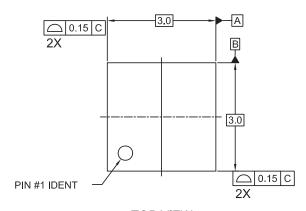
Figure 17. Recommended PCB Layout

Use wide traces for high-current paths and place the input capacitor, the inductor, and the output capacitor as close as possible to the integrated circuit terminals. To minimize voltage stress to the device resulting from everpresent switching spikes, use an input bypass capacitor with low ESR. Note that the peak amplitude of the switching spikes depends upon the load current; the higher the load current, the higher the switching spikes. The resistor divider that sets the output voltage should be routed away from the inductor to avoid RF coupling. The ground plane at the bottom side of the PCB acts as an electromagnetic shield to reduce EMI.

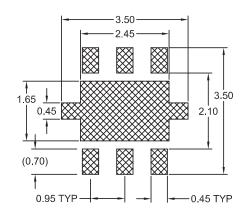
For more board layout recommendations, download the Fairchild application note *PCB Grounding System and FAN2001/FAN2011 High-Performance DC-DC Converters* (AN-42036).

## **Mechanical Dimensions**

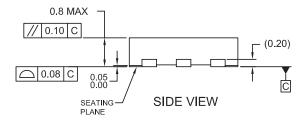
Dimensions are in millimeters unless otherwise noted.

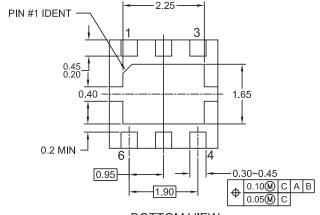


**TOP VIEW** 



RECOMMENDED LAND PATTERN





## BOTTOM VIEW

## NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-229, VARIATION WEEA, DATED 11/2001 EXCEPT FOR DAP EXTENSION TABS
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

MLP06FrevA

Figure 18. 3x3mm 6-Lead MLP





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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild Semiconductor. The datasheet is printed for reference information only.

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